										RE	EVIS	ION	 S												
LTR							DES	CRIP	TION						·			DAT	E (YF	I-MO-	DA)	A	PPR	OVED	
Α	Cha Edi	nge (_j torial	N ar	nd C _C	OUT (imit ough	s. out.	Add	ac t	est	poir	nts t	o f	igur	e 4.			198	8 SE	P 29	,	14	-1	M	<u></u>
В	to	le I, group e outl	A ir	spec	tion	. А	dded	dev	ice	type	s 03	and						198	9 SE	P 14		1/2	1	Poet Poet	<u>Z</u>
с	cha fig	hnical nges t ure 1, oughou	o ta	ble	I.	Clar	ific	atio	ns a	ind c	orre	ctic	ns c		l			91	-09	9-24	1	Ŋ.	<i>-</i>	Poet	K,
REV		1																I						I	
REV ·																									
	C	: C	С	С																					
SHEET		2 23	24																						
SHEET	rus	2 23 RE	24 E V	25	c	C	C	C	C	C	C	C		C	C	С	C	C	C	C	C	C	c	C	C
SHEET REV SHEET REV STAT OF SHEE	rus Ts	2 23 RE	24	25	1	2	3	4	C 5	C 6	C 7	C 8		c 10	c 111	C 12	<u> </u>		C 15	 		_	-	c 20	
SHEET REV SHEET REV STATOF SHEE PMIC N/A	rus its	2 23 RE SH	24 EV	25	1 PRE	2 PARE CKE	3 D BY	4	5	6	-	8			11	-	13 E EL!	14	15 ONIC	16 S S	17 UPPL	18 Y CE	19	20	
SHEET REV SHEET REV STAT OF SHEE PMIC N/A STANI	TUS ITS DARI LITA	2 23 RE SH DIZE RY	24 EV HEET	25	1 PRE	PARE CKEL	3 ED BY ED BY	4	5 V.	6	7	8	9	10	DEF	12	13 E ELI DA	14 ECTR YTO	15 ONK	16 S SI	17 UPPL 5444	18 Y CE	19	20	
SHEET REV SHEET REV STAT OF SHEE PMIC N/A STANI DR THIS DRAF	DARI LITA AWII wing is	PARTIES OF THE	24 EV HEET	25	CHE APE	PARE CKEI	3 ED BY	4 PROV	5 V.	6	7	8	9 M D	10	DEF	ENSI CUITS CHMC	13 E ELI DA S, 3	14 ECTR YTO	ONK I, OF	16 CS SI	17 S444 ROCE	18 Y CE	19	20	21

DESC FORM 193 SEP 87

+ U.S. GOVERNMENT PRINTING OFFICE: 1987 - 748-129/60911

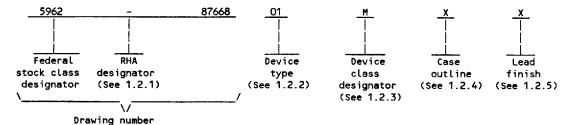
5962-E269

DISTRIBUTION STATEMENT A. Approved for public release; distribution is unlimited.

■ 9004708 0010654 076 ■ 3

1. SCOPE

- 1.1 <u>Scope</u>. This drawing forms a part of a one part one part number documentation system (see 6.6 herein). Two product assurance classes consisting of military high reliability (device classes B, Q, and M) and space application (device classes S and V), and a choice of case outlines and lead finishes are available and are reflected in the Part or Identifying Number (PIN). Device class M microcircuits represent non-JAN class B microcircuits in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices". When available, a choice of radiation hardness assurance (RHA) levels are reflected in the PIN.
 - 1.2 PIN. The PIN shall be as shown in the following example:



- 1.2.1 <u>Radiation hardness assurance (RHA) designator</u>. Device classes M, B, and S RHA marked devices shall meet the MIL-M-38510 specified RHA levels and shall be marked with the appropriate RHA designator. Device classes Q and V RHA marked devices shall meet the MIL-I-38535 specified RHA levels and shall be marked with the appropriate RHA designator. A dash (-) indicates a non-RHA device.
 - 1.2.2 <u>Device type(s)</u>. The device type(s) shall identify the circuit function as follows:

Device type	Generic number	Circuit function	Frequency
01	80386-16	32-bit microprocessor	16 MHz
02	80386-12	32-bit microprocessor	12.5 MHz
03	80386-20	32-bit microprocessor	20 MHz
04	80386-25	32-bit microprocessor	25 MHz

1.2.3 <u>Device class designator</u>. The device class designator shall be a single letter identifying the product assurance level as follows:

Device class	Device requirements documentation						
M	Vendor self-certification to the requirements for non-JAN class B microcircuits in accordance with 1.2.1 of MIL-STD-883						
B or S	Certification and qualification to MIL-M-38510						
Q or V	Certification and qualification to MIL-I-38535						

STANDARDIZED MILITARY DRAWING	SIZE A		5962-87668
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL	SHEET 2

DESC FORM 193A JUL 91

9004708 0010655 TO2 **=**

1.2.4 <u>Case outline(s)</u>. For device classes M, B, and S, case outline(s) shall meet the requirements in appendix C of MIL-M-38510 and as listed below. For device classes Q and V, case outline(s) shall meet the requirements of MIL-I-38535, appendix C of MIL-M-38510, and as listed below.

Outline letter

Case outline

X P-AF (132-terminal, 1.480" x 1.480" x .345"), pin grid array
Y See figure 1 (164-terminal, 1.140" x 1.140" x .115"), leaded chip carrier with unformed leads

1.2.5 <u>Lead finish</u>. The lead finish shall be as specified in MIL-M-38510 for classes M, B, and S or MIL-I-38535 for classes Q and V. Finish letter "X" shall not be marked on the microcircuit or its packaging. The "X" designation is for use in specifications when lead finishes A, B, and C are considered acceptable and interchangeable without preference.

1.3 Absolute maximum ratings.

1.4 Recommended operating conditions.

1.5 Digital logic testing for device classes Q and V.

Fault coverage measurement of manufacturing logic tests (MIL-STD-883, test method 5012) - - - - - 98.4 percent

STANDARDIZED MILITARY DRAWING	SIZE A		5962-87668
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL	SHEET 3

DESC FORM 193A

JUL 91

9004708 0010656 949 **5**

2. APPLICABLE DOCUMENTS

2.1 <u>Government specifications, standards, bulletin, and handbook</u>. Unless otherwise specified, the following specifications, standards, bulletin, and handbook of the issue listed in that issue of the Department of Defense Index of Specifications and Standards specified in the solicitation, form a part of this drawing to the extent specified herein.

SPECIFICATIONS

MILITARY

MIL-M-38510

Microcircuits, General Specification for.

MIL-I-38535

Integrated Circuits, Manufacturing, General Specification for.

STANDARDS

MILITARY

MIL-STD-480

Configuration Control-Engineering Changes, Deviations and Waivers.

MIL-STD-883 -

Test Methods and Procedures for Microelectronics.

BULLETIN

MILITARY

MIL-BUL-103

- List of Standardized Military Drawings (SMD's).

HANDBOOK

MILITARY

MIL-HDBK-780

Standardized Military Drawings.

(Copies of the specifications, standards, bulletin, and handbook required by manufacturers in connection with specific acquisition functions should be obtained from the contracting activity or as directed by the contracting activity.)

2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence.

3. REQUIREMENTS

- 3.1 <u>Item requirements</u>. The individual item requirements for device class M shall be in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices" and as specified herein. The individual item requirements for device classes B and S shall be in accordance with MIL-M-38510 and as specified herein. For device classes B and S, a full electrical characterization table for each device type shall be included in this SMD. The individual item requirements for device classes Q and V shall be in accordance with MIL-I-38535, the device manufacturer's Quality Management (QM) plan, and as specified herein.
- 3.2 <u>Design, construction, and physical dimensions</u>. The design, construction, and physical dimensions shall be as specified in MIL-M-38510 for device classes M, B, and S and MIL-I-38535 for device classes Q and V and herein.
 - 3.2.1 Case outline(s). The case outline(s) shall be in accordance with 1.2.4 herein and figure 1.
 - 3.2.2 <u>Terminal connections</u>. The terminal connections shall be as specified on figure 2.
 - 3.2.3 Block diagram. The block diagram shall be as specified on figure 3.

STANDARDIZED MILITARY DRAWING	SIZE A		5962-87668
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL C	SHEET 4

DESC FORM 193A JUL 91

9004708 0010657 885

- 3.3 <u>Electrical performance characteristics and postirradiation parameter limits</u>. Unless otherwise specified herein, the electrical performance characteristics and postirradiation parameter limits are as specified in table I and shall apply over the full case operating temperature range.
- 3.4 <u>Electrical test requirements</u>. The electrical test requirements shall be the subgroups specified in table IIA. The electrical tests for each subgroup are defined in table I.
- 3.5 <u>Marking</u>. The part shall be marked with the PIN listed in 1.2 herein. Marking for device class M shall be in accordance with MIL-STD-883 (see 3.1 herein). In addition, the manufacturer's PIN may also be marked as listed in MIL-BUL-103. Marking for device classes B and S shall be in accordance with MIL-M-38510. Marking for device classes Q and V shall be in accordance with MIL-I-38535.
- 3.5.1 <u>Certification/compliance mark</u>. The compliance mark for device class M shall be a "C" as required in MIL-STD-883 (see 3.1 herein). The certification mark for device classes B and S shall be a "J" or "JAN" as required in MIL-M-38510. The certification mark for device classes Q and V shall be a "QML" as required in MIL-I-38535.
- 3.6 <u>Certificate of compliance</u>. For device class M, a certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-BUL-103 (see 6.7.3 herein). For device classes Q and V, a certificate of compliance shall be required from a QML-38535 listed manufacturer in order to supply to the requirements of this drawing (see 6.7.2 herein). The certificate of compliance submitted to DESC-ECC prior to listing as an approved source of supply for this drawing shall affirm that the manufacturer's product meets, for device class M the requirements of MIL-STD-883 (see 3.1 herein), or for device classes Q and V, the requirements of MIL-I-38535 and the requirements herein.
- 3.7 <u>Certificate of conformance</u>. A certificate of conformance as required for device class M in MIL-STD-883 (see 3.1 herein) or device classes B and S in MIL-M-38510 or for device classes Q and V in MIL-I-38535 shall be provided with each lot of microcircuits delivered to this drawing.
- 3.8 Notification of change for device class M. For device class M, notification to DESC-ECC of change of product (see 6.2 herein) involving devices acquired to this drawing is required for any change as defined in MIL-STD-480.
- 3.9 <u>Verification and review for device class M</u>. For device class M, DESC, DESC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.
- 3.10 <u>Microcircuit group assignment for device classes M, B, and S</u>. Device classes M, B, and S devices covered by this drawing shall be in microcircuit group number 105 (see MIL-M-38510, appendix E).
- 3.11 <u>Serialization for device class S</u>. All device class S devices shall be serialized in accordance with MIL-M-38510.
 - 3.12 PIN supersession information. The PIN supersession information shall be as specified in the appendix.
 - 4. QUALITY ASSURANCE PROVISIONS
- 4.1 <u>Sampling and inspection</u>. For device class M, sampling and inspection procedures shall be in accordance with section 4 of MIL-M-38510 to the extent specified in MIL-STD-883 (see 3.1 herein). For device classes B and S, sampling and inspection procedures shall be in accordance with MIL-M-38510 and method 5005 of MIL-STD-883, except as modified herein. For device classes Q and V, sampling and inspection procedures shall be in accordance with MIL-I-38535 and the device manufacturer's QM plan.
- 4.2 <u>Screening</u>. For device class M, screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. For device classes B and S, screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to qualification and quality conformance inspection. For device classes Q and V, screening shall be in accordance with MIL-I-38535, and shall be conducted on all devices prior to qualification and technology conformance inspection.

STANDARDIZED
MILITARY DRAWING
DEFENSE ELECTRONICS SUPPLY CENTER
DAYTON, OHIO 45444

SIZE
A

REVISION LEVEL
SHEET
C
5

DESC FORM 193A JUL 91

■ 9004708 0010658 711 ■

4.2.1 Additional criteria for device classes M, B, and S.

- a. Burn-in test, method 1015 of MIL-STD-883.
 - (1) Test condition A, B, C, or D. For device class M, the test circuit shall be submitted to DESC-ECC for review with the certificate of compliance. For device classes B and S, the test circuit shall be submitted to the qualifying activity.
 - (2) $T_A = +125$ °C, minimum.
- b. Interim and final electrical test parameters shall be as specified in table IIA herein.

4.2.2 Additional criteria for device classes Q and V.

- a. The burn-in test duration, test condition and test temperature or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-I-38535. The burn-in test circuit shall be submitted to DESC-ECC with the certificate of compliance and shall be under the control of the device manufacturer's Technology Review Board (TRB) in accordance with MIL-I-38535.
- b. Interim and final electrical test parameters shall be as specified in table IIA herein.
- c. Additional screening for device class V beyond the requirements of device class Q shall be as specified in appendix B of MIL-I-38535 and as detailed in table IIB herein.

4.3 Qualification inspection.

- 4.3.1 Qualification inspection for device classes B and S. Qualification inspection for device classes B and S shall be in accordance with MIL-M-38510. Inspections to be performed shall be those specified in method 5005 of MIL-STD-883 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.5).
- 4.3.2 Qualification inspection for device classes Q and V. Qualification inspection for device classes Q and V shall be in accordance with MIL-I-38535. Inspections to be performed shall be those specified in MIL-I-38535 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.5).
- 4.4 <u>Conformance inspection</u>. Quality conformance inspection for device class M shall be in accordance with MIL-STD-883 (see 3.1 herein) and as specified herein. Quality conformance inspection for device classes B and S shall be in accordance with MIL-M-38510 and as specified herein. Inspections to be performed for device classes M, B, and S shall be those specified in method 5005 of MIL-STD-883 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.5). Technology conformance inspection for classes Q and V shall be in accordance with MIL-I-38535 including groups A, B, C, D, and E inspections and as specified herein except where option 2 of MIL-I-38535 permits alternate in-line control testing.

4.4.1 Group A inspection.

- a. Tests shall be as specified in table IIA herein.
- b. Supgroups 5 and 6 in table I, method 5005 of MIL-STD-883 shall be omitted.
- c. Subgroup 4 (C_{IO} measurement) shall be measured only for the initial test and after process or design changes which may affect capacitance. A minimum sample size of five devices with zero rejects shall be required.
- d. For device class M, subgroups 7 and 8 tests shall include verification of the device functionality. These tests shall be maintained and available from the approved source of supply upon request. For device classes B and S, subgroups 7 and 8 tests shall include verification of the device functionality. For device classes Q and V, subgroups 7 and 8 shall include verifying the functionality of the device; these tests shall have been fault graded in accordance with MIL-STD-883, test method 5012 (see 1.5 herein).

STANDARDIZED MILITARY DRAWING	SIZE A		5962 -87668
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL C	SHEET 6

DESC FORM 193A

JUL 91

■ 9004708 0010659 658 **■**

		TABLE I. Electrical perfe	ormance char	acteristic	<u>s</u> .		
Test	Symbol	Conditions 1/ 4.75 V ≤ V _{CC} ≤ 5.25 V -55°C ≤ T _C ≤ +125°C unless otherwise specified	Group A	Device	<u>Limi</u>	ts	Unit
		unless otherwise specified	subgroups	type	Min	Max	
Input low voltage	VIL		1, 2, 3	ALL	-0.3 <u>2</u> /	0.8	٧
Input high voltage	v _{IH}		1, 2, 3	ALL	2.0	v _{cç0.3}	
CLK2 input low voltage	VILC		1, 2, 3	ALL	-0.3 <u>2</u> /	0.8	
CLK2 input high voltage	VIHC		1, 2, 3	All	v _{cc} _{0.8}	v _{cç0.3} 2/	
Output low voltage	V _{OL}	I _{OL} = 4 mA: A2-A31, DO-D31	1, 2, 3	ALL		0.45	
		I _{OL} = 5 mA: BEO-BE3, W/R, D/C, M/IO, LOCK, ADS, HLDA				0.45	
Output high voltage	V _{ОН}	I _{OH} = -1 mA; A2-A31, D0-D31	1, 2, 3	ALL	2.4		}
		I _{OH} =9 mA: BEO-BE3, W/R, D/C, M/IO, LOCK, ADS, HLDA			2.4		
Input leakage current (for all pins except BS16, PEREQ, BUSY, and ERROR)	ILI	o v < v _{in} < v _{cc}	1, 2, 3	All	-15	+15	μA
Input leakage current (PEREQ pin)	IIH	V _{IH} = 2.4 V	1, 2, 3	All		200	
Input leakage current (BS16, BUSY, and ERROR pins)	IIL	V _{IL} = 0.45 V	1, 2, 3	ALL		-400	

STANDARDIZED MILITARY DRAWING	SIZE A		5962 -87668
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL C	SHEET 7

DESC FORM 193A JUL 91

■ 9004708 0010660 37T **■**

Test	Symbol	Conditions 1/ 4.75 V ≤ V _{oo} ≤ 5.25 V	 Group A	Device	Limits		Unit
		4.75 V ≤ Vcc ≤ 5.25 V -55°C ≤ T _C ≤ +125°C unless otherwise specified	subgroups	type	Min	Max	
Output leakage current	ILO	0.45 V < V _{OUT} < V _{CC}	1, 2, 3	All	-15	+15	μA
Supply current	Icc	CLK2 = 32 MHz	1, 2, 3	01		450	mA
		CLK2 = 25 MHz	<u> </u>	02	_	400	
		CLK2 = 40 MHz	1	03		550	
		CLK2 = 50 MHz		04		680	
Input capacitance	cIN	Fc = 1 MHz, see 4.4.1c	4	ALL		20	pF
Output or I/O capacitance	C _{OUT}		4	All		25	
CLK2 capacitance	CCLK		4	All		20	•
Functional tests		V _{CC} = 4.75 V, 5.25 V, see 4.4.1d	7, 8	ALL			
Operating frequency		Half of CLK2 frequency	<u> </u>	01	4	16	MHz
				02		12.5	1
				03		20	1
	<u> </u>			04		25	
CLK2 period	t ₁	See figure 4	9, 10, 11	01	30	125	ns
				02	40		
				03	25		
				04	20		<u> </u>
CLK2 high time	t _{2a}	At 2 V	9, 10, 11	01	9		
		See figure 4		_02	11		
				03	8		
				nΔ	ż		

STANDARDIZED MILITARY DRAWING	SIZE A		5962-87668
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL	SHEET 8

DESC FORM 193A JUL 91

9004708 0010661 206

Test	Symbol	Conditions $\frac{1}{4.75}$ V \leq V _{CC} \leq 5.25 V	Group A subgroups	Device	Limit	s	Unit
1630	J This c	4.75 V ≤ V _{CC} ≤ 5.25 V -55°C ≤ T _C ≤ +125°C unless otherwise specified		type	Min	Max	
CLK2 high time	t _{2b}	At (V _{CC} -0.8 V) See figure 4	9, 10, 11	01	5		ns
		See figure 4 		_02	7		
				_03	5		
				04	4		•
CLK2 low time	t _{3a}	At 2 V	9, 10, 11	01	9		
		See figure 4		02	11		
				03	8		
				04	7		-
CLK2 low time	t _{3b}	At 0.8 V See figure 4	9, 10, 11	01			
<u>2</u> /		See Tigure 4		02	9		
				03	6		
	ļ			04	5		+
CLK2 fall time 2/	t ₄	(V _{CC} -0.8 V) to 0.8 V See figure 4	9, 10, 11	01, 02 03		8	
		See Figure 4		04		7	
CLK2 rise time 2/	1	0.8 V to (V =0.8 V)	9, 10, 11	01, 02		8	†
CERE 115e CIME <u>2</u> 7	t ₅	0.8 V to (V _{CC} -0.8 V) See figure 4		03			
	ļ			04		7	
A2-A31 valid delay	t ₆	C = 120 pF See figure 4	9, 10, 11	01	4	36	<u> </u>
<u>3</u> /		l see riggie 4		02	2	44	+
				03	4	27	+
				04	4	20	+
A2-A31 float delay <u>2</u> / <u>4</u> /	t ₇	See figure 4	9, 10, 11	01	4	40	+
£, 3,				02	1	45	+
				03	4	32	+
	<u> </u>		İ	04	4	30	<u> </u>

STANDARDIZED MILITARY DRAWING		SIZE A		5962-87668
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL	SHEET 9	
DESC FORM 193A JUL 91	™ 9004708 0010662	. 142 💻		

Test	Symbol	Conditions 1/	Group A	Device	Limi	ts	Unit
		-55°C ≤ T _C ≤ +125°C unless otherwise specified	subgroups	type	Min	Max	
EO-BE3, LOCK,	t ₈	c _l = 75 pF See figure 4	9, 10, 11	01	4	36	ns
valid delay		See Tigure 4		02	2	44	
<u>3</u> /				03	4	27	
				04	4	24	
BE3, LOCK,	t ₉	See figure 4	9, 10, 11	01	4	40	
float delay 2/4/				02	1	45	_
	ļ			03	4	32	
				04	4	30	
<u>R, M/IO, D/C,</u>	t ₁₀	c_ = 75 pF	9, 10, 11	01	6	33	1
ADS valid delay	1	See figure 4		02	5	39	1
<u>3</u> /				_ 03	6	28	
				04	4	19	1
_M/IO, D/C,	t ₁₁	See figure 4	9, 10, 11	01	6	35	_
NDS float delay 2/4/				_02	4	40	1
				03	6	30	_
				04	4	30	1
-D31 write data	t ₁₂	c, = 120 pF	9, 10, 11	01	4	48	_
valid delay	'-	See figure 4		02	2	54	_
<u>3</u> /				03	6	38	
				04	8	27	
-D31 write data	t ₁₃	See figure 4	9, 10, 11	01	4	35	_
float delay <u>2</u> / <u>4</u> /	'3	_		02	111	44	_
	<u> </u>			03	4	27	_
				04	4	22	

STANDARDIZED MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444	SIZE A		5962-87668
		REVISION LEVEL	SHEET 10

DESC FORM 193A

JUL 91

■ 9004708 0010663 089 **■**

Test	Symbol	Conditions 1/	Group A	Device	<u>Limit</u>	٠٩	Unit
	Symbol	4.75 V ≤ V _{CC} ≤ 5.25 V -55°C ≤ T _C ≤ +125°C unless otherwise specified	subgroups	type	Min	Max	John
HLDA valid delay	t ₁₄	C _L = 75 pF See figure 4	9, 10, 11	01	6	33	_ ns
<u>3</u> /		See figure 4		02	3	39	_
				03	6	28	_
				04	4	22	_
NA setup time	t ₁₅	 See figure 4	9, 10, 11	01	11		
				02	15		
				03	9		
				04	7		
NA hold time	t ₁₆		9, 10, 11	01	14		
				02	23		
				03	14		
				04	3		
3S16 setup time	t ₁₇		9, 10, 11	01	13		
	"			02	13		
				03	13	 	
				04	7	[
SS16 hold time	t ₁₈		9, 10, 11	01	21]	
	10			02	23	 	
				03	21		
				04	3		
READY setup time	t ₁₉		9, 10, 11	01	21		
	-19			02	23		
				03	12		
				04	8		

STANDARDIZED MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444	SIZE A		5962-87668
		REVISION LEVEL	SHEET 11

DESC FORM 193A JUL 91

9004708 0010664 T15 **=**

Test	Symbol	Conditions 1/ 4.75 V ≤ V _{CC} ≤ 5.25 V	Group A	Device	Limi1	ts	Unit
		4.75 V \leq V _{CC} \leq 5.25 V -55°C \leq T _C \leq +125°C unless otherwise specified	subgroups	type	Min	Max	
READY hold time	t ₂₀	See figure 4	9, 10, 11	01	4		ns
				02	6		ļ
				03	4		
				04	4		
00-031 read setup	t ₂₁		9, 10, 11	01	11		
time		,		02	13		
	į			03	11		
				04	6		
00-031 read hold time	t ₂₂		9, 10, 11	01	6		
time				02	8		
				03	6		
	 		<u> </u>	04	5		
OLD setup time	t ₂₃		9, 10, 11	01	26	•	
				02	28		
				03	17		
				04	15		
HOLD hold time	^t 24		9, 10, 11	01	5		
			<u> </u>	02	6		[
				03	5		
				04	3		
RESET setup time	^t 25		9, 10, 11	01	13		
				02	16		
				03	12		
				04	10		

STANDARDIZED MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444	SIZE A		5962-87668
		REVISION LEVEL C	SHEET 12

DESC FORM 193A

JUL 91

: 🔤 9004708 0010665 951 📟

	TA	BLE I. Electrical performance	characteris	<u>tics</u> - Co	ntinued.		
Test	Symbol	Conditions $\frac{1}{4.75}$ V \leq V _{CC} \leq 5.25 V	Group A	Group A Device	vice <u>Limits</u>		Unit
		4.75 V ≤ V_{CC} ≤ 5.25 V -55°C ≤ T_C ≤ +125°C unless otherwise specified	subgroups	type	Min	Max	
RESET hold time	^t 26	See figure 4	9, 10, 11	01, 02 03	4		ns
-	<u> </u>		<u> </u>	04	3		
NMI, INTR setup	t ₂₇		9, 10, 11	01	16]	
time <u>5</u> /	-			02	19		
				03	16		
	ļ 			04	6		
NMI, INTR hold time	t ₂₈		9, 10, 11	01	16		
time <u>5</u> /				02	19	.]	
				_03	16		
				04	6		
PEREQ, ERROR, BUSY	t ₂₉		9, 10, 11	01	16		
setup time <u>5</u> /			† 	02	19	.	
				03	14		
	<u> </u>			04	6	ļ	
PEREQ, ERROR, BUSY hold time 5/	t ₃₀		9, 10, 11	ALL	5		

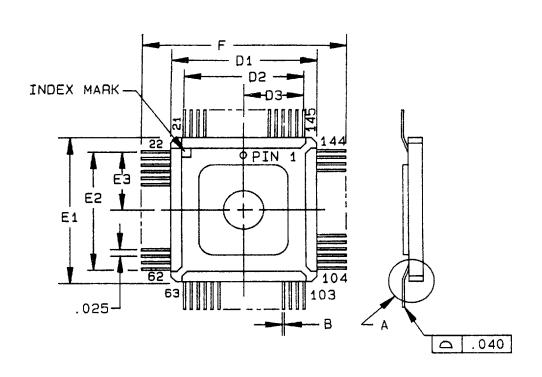
- $\underline{1}/$ All tests shall be performed using the worst case conditions, unless otherwise specified.
- 2/ Guaranteed if not tested to the limits specified.
- 3/ For 25 MHz, $C_L = 50$ pF.
- $\underline{4}/$ Float condition occurs when maximum output current becomes less than I_{LO} in magnitude.
- 5/ These inputs are allowed to be asynchronous to CLK2. The setup and hold specifications are given for testing purposes to assure recognition within a specific CLK2 period.

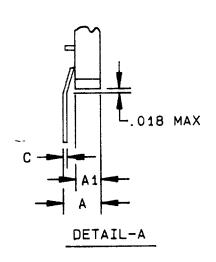
STANDARDIZED MILITARY DRAWING	SIZE		5962-87668
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL	SHEET

DESC FORM 193A

JUL 91

: **5** 9004708 0010666 **898**





Symbol	Inches		Millin	neters
	Min	Max	Min	Max
A	.086	.115	2.18	2.92
A1	.078	.094	1.98_	2.39
8	.007	.010	0.18	0.25
С	.004	.006	0.10	0.15
D1, E1	1		28.45	
D2, E2	1.000	1	28.40	
D3, E3	.500 BSC		12.70	
νο, εο F	1	1	62.74	

NOTES:

 Dimensions are in inches.
 Metric equivalents are given for general information only.
 Symbols B and C dimensions shall be increased by .002 inch (0.05 mm) when soldering coat is added.

FIGURE 1. Case outline Y.

STANDARDIZED MILITARY DRAWING	SIZE A		5962-87668
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL C	SHEET 14

DESC FORM 193A JUL 91

■ 9004708 0010667 724 ■

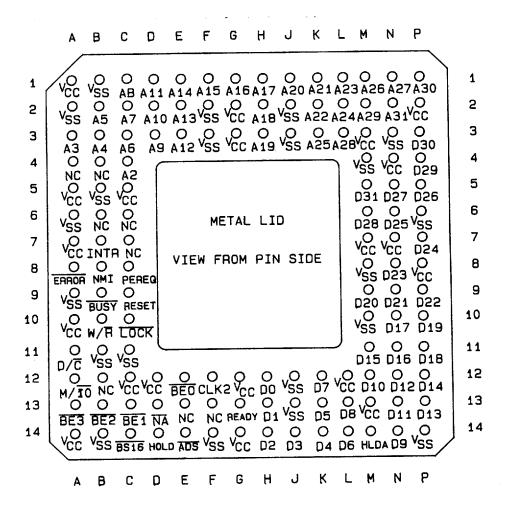


FIGURE 2. Terminal connections.

STANDARDIZED MILITARY DRAWING	SIZE A		5962-87668
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL	SHEET 15

DESC FORM 193A

JUL 91

9004708 0010668 660

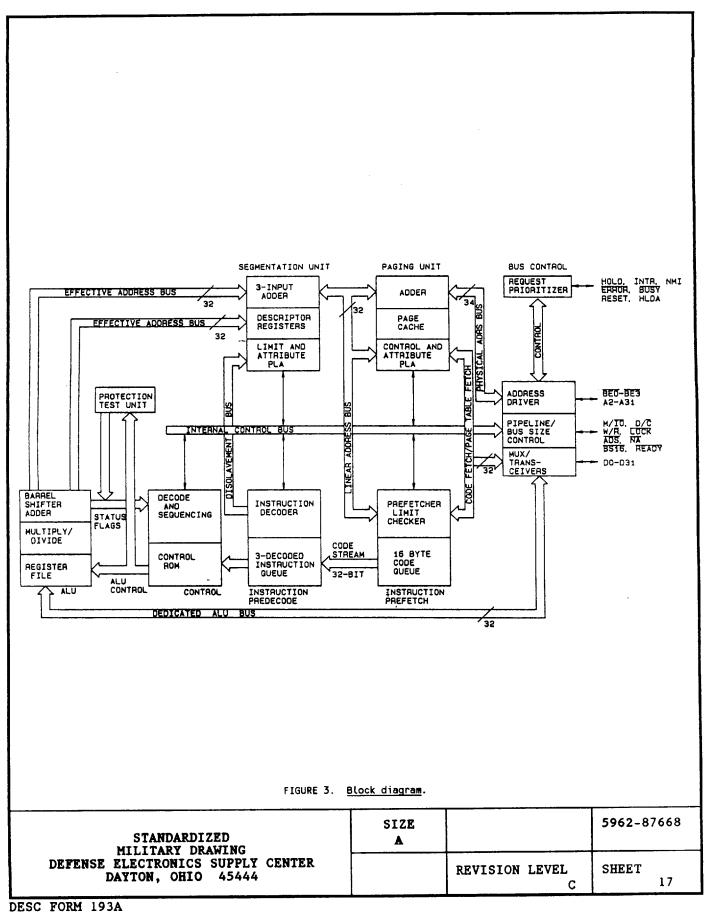
Device types	All	Device types	ALL	Device types	All	Device types	All
Case	Y	Case	Y	Case	Υ	Case	Y
outline		outline		outline_		outline	
			T		Tanning		Terminal
Terminal	Terminal	Terminal		Terminal	Terminal symbol	Terminal	symbot
number	symbol	number	symbol	number	Symbol	number	SYMBOL
01	A16	42	PEREQ	83	READY	124	D19
02	A17	1 43		84	NC	125	NC
03	A15	44	vss	85	D1	126	NC
04	A14	45	V _{SS} V _{CC} ERROR	86	NC	127	D24
05	A13	46	RESET	87	D2	128	D21
06	A12	47	NC	88	NC	129	NC
07	A11	48	NC	89	D4	130	NC
08	NC NC	49	BUSY	90	DO	131	D25
09	A9	50	v _{cc}	91	V _{CC}	132	D23
10	A10	51	V.CC	92	v CC	133	NC
11		1 52	vss vcc	93	v _Š s D6	134	NC
12	V _S S A7	53	V.CC	94	D3	135	D27
13	A8	54	VSS	95		136	026
14		55	VCC	96	vss v	137	
15	Vcc	1 56	vss v	97	v 55 D8	138	v _{cc}
16	V _{SS} A5	57	Vcc	98	D5	139	V SS D29
17	A6	58	vss vss	99		140	p28
18	NC	1 59	V СС LO <u>С</u> К	100	Vcc	141	
19	NC	60	W/R	100	VSS HLDA	142	Vcc
20	A3	60		102	D7	143	v 55 p31
21	A4	62	vss	1 103	NC NC	144	030
22	NC	62	v ³³ м/10	103	D10	145	NC
23		65	D/C	104	D10	145	A31
	NC	65	NC	105 1 106	NC	147	A30
24	A2	11 1			NC NC	147	A29
25	NC	66	NC_	107		146 149	
26	^V cc	67	BE2	108	D12 D11	[] 149 [] 150	A28
27	V _{SS} NC	68	NC	109		• •	Vcc
28		69	Vcc	110	V _{CC}	151	V _{SS} A27
29	NC	70	VSS BEO	111	v _{SS} D14	152	
30	NC	71		112		153	A26
31	Vcc	72	BE3	113	D13	154	A25
32	V SS NČ	73	NC_	114	NC	155	NC
33		74	BE1	115	D15	156	A23
34	Vcc	75	NA	116	D16	157	A24
35	V SS NČ	76	NC	117	Vcc	158	A21
36		77	NC	118	v SS p18	159	A22
37	INTR	78	BS16	119		160	NC
38	NC	79	HOLD	120	D17	161	A20
39	NC	80	<u>clk</u> 2	121	D2 O	162	A19
40	NC	81	ADS	122	v pžž	163	A18
41	NMI	82	NC	123	DŽŽ	164	NC

FIGURE 2. <u>Terminal connections</u> - Continued.

STANDARDIZED MILITARY DRAWING	SIZE A		5962-87668
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL C	SHEET 16

DESC FORM 193A JUL 91

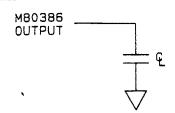
■ 9004708 0010669 5T7 ■



ESC FORM 193A JUL 91

3004708 0010670 219

AC TEST LOADS



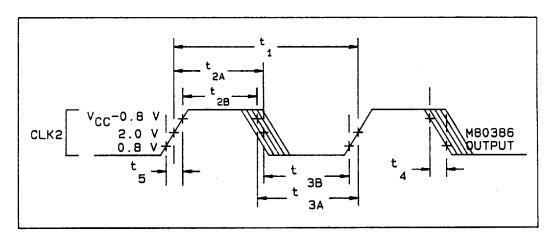
C1 =120 pF ON A2-A31, D0-D31

 C_L =75 pF ON $\overline{BEO}-\overline{BE3}$, W/ \overline{A} , M/ \overline{IO} , D/ \overline{C} , \overline{ADS} , \overline{LOCK} , HLDA

 \mathbf{C}_{L} includes all parasitic capacitances

 $C_1 = 50$ pF FOR 25 MHz

AC TIMING WAVEFORMS



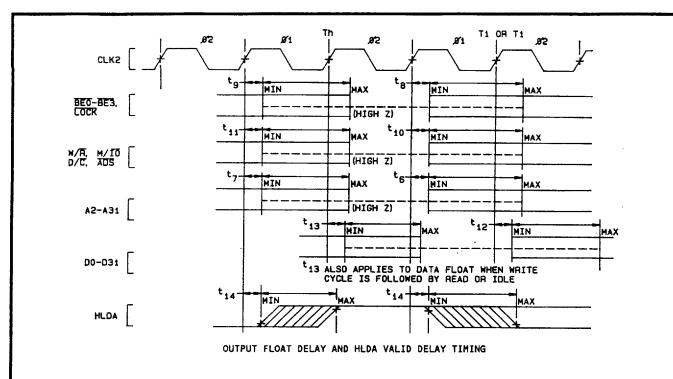
CLK2 TIMING

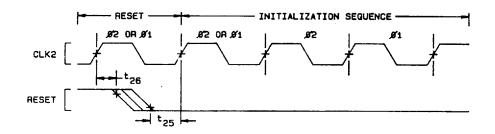
FIGURE 4. Test circuit and switching waveforms.

STANDARDIZED MILITARY DRAWING	SIZE A		5962-87668
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL C	SHEET 18

DESC FORM 193A JUL 91

9004708 0010671 155 **=**





The second internal processor phase following RESET high-to-low transition (provided $\rm t_{25}$ and $\rm t_{26}$ are met) is $\phi 2.$

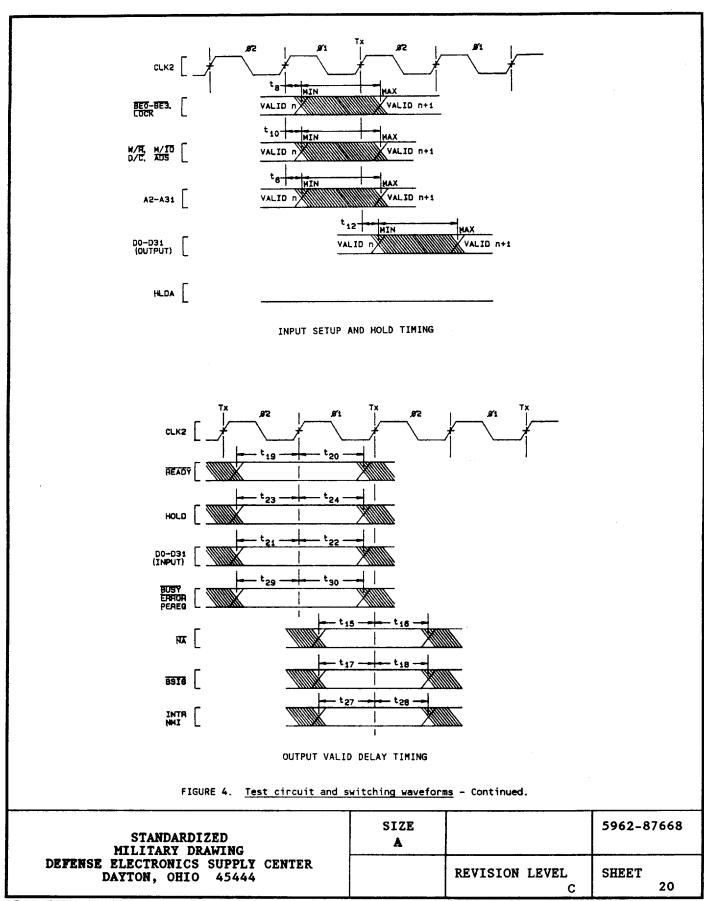
RESET SETUP AND HOLD TIMING, AND INTERNAL PHASE

FIGURE 4. Test circuit and switching waveforms - Continued.

STANDARDIZED MILITARY DRAWING	SIZE A		5962-87668
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL C	SHEET

DESC FORM 193A JUL 91

- 9004708 0010672 091 **-**



DESC FORM 193A JUL 91

📟 9004708 0010673 T28 📟

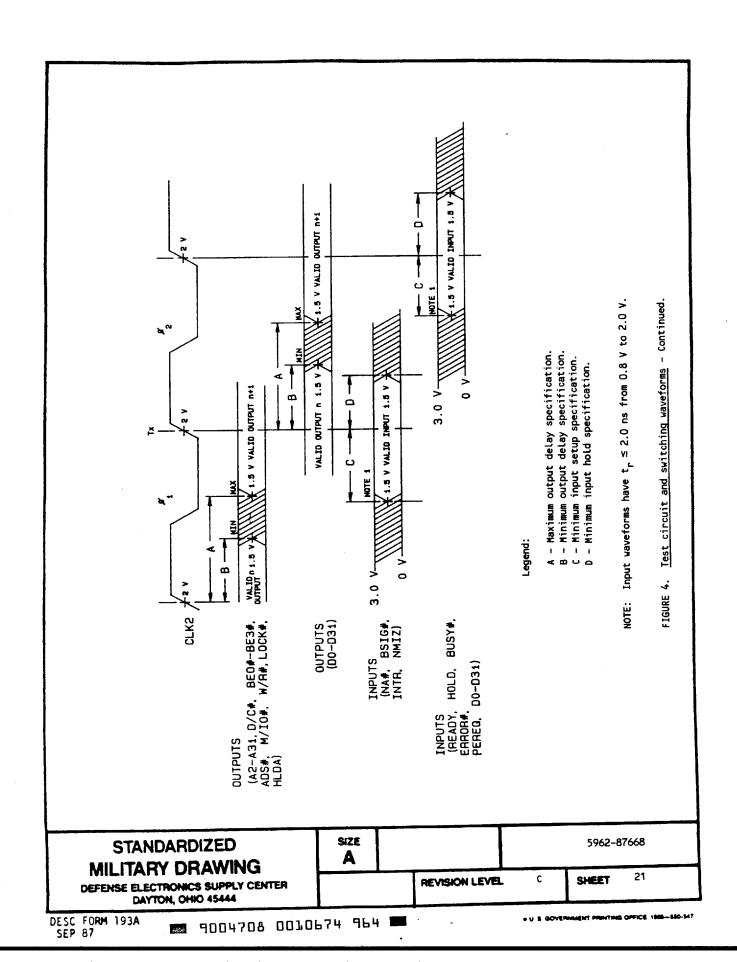


TABLE IIA. <u>Electrical test requirements</u>.

Test requirements	Subgroups (per method 5005, table I)			Subgroups (per MIL-I-38535, table III)	
	Device class M	Device class	Device class S	Device class Q	Device class V
Interim electrical parameters (see 4.2)		 	1,7,9		1,7,9
Final electrical parameters (see 4.2)		1,2,3,7,8 9,10,11 2/		1,2,3,7,8 9,10,11 1/	
Group A test requirements (see 4.4)	1,2,3,4,7 8,9,10,11			1,2,3,4,7	
 Group B end-point electrical parameters (see 4.4)		 	2,8,10		2,8,10
Group C end-point electrical parameters (see 4.4)	2,8A,10	2,8,10		2,8,10	
Group D end-point electrical parameters (see 4.4)	2,8A,10	2,8,10	2,8,10	2,8,10	2,8,10
Group E end-point electrical parameters (see 4.4) 1/ PDA applies to subgroup 1	1,7,9	1,7,9	1,7,9	1,7,9	1,7,9

1/ PDA applies to subgroup 1.

- 4.4.2 <u>Group B inspection</u>. The group B inspection end-point electrical parameters shall be as specified in table IIA herein.
- 4.4.3 <u>Group C inspection</u>. The group C inspection end-point electrical parameters shall be as specified in table IIA herein.
- 4.4.3.1 Additional criteria for device classes M, B, and S. Steady-state life test conditions, method 1005 of MIL-STD-883:
 - a. Test condition A, B, C, or D. For device class M, the test circuit shall be submitted to DESC-ECC for review with the certificate of compliance. For device classes B and S, the test circuit shall be submitted to the qualifying activity.
 - b. $T_A = +125$ °C, minimum.
 - c. Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.
- 4.4.3.2 <u>Additional criteria for device classes Q and V</u>. The steady-state life test duration, test condition and test temperature or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-I-38535. The steady-state life test circuit shall be submitted to DESC-ECC with the certificate of compliance and shall be under the control of the device manufacturer's TRB in accordance with MIL-I-38535.

STANDARDIZED MILITARY DRAWING	SIZE A		5962-87668
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL	SHEET 22

DESC FORM 193A JUL 91

9004708 0010675 8TO **1**

^{2/} PDA applies to subgroups 1 and 7.

TABLE IIB. Additional screening for device class V.

Test	MIL-STD-883, test method	Lot requirement
Particle impact noise detection	2020	100%
Internal visual	2010, condition A or approved alternate	100%
Nondestructive bond pull	2023 or approved alternate	100%
Reverse bias burn-in	1015	100%
Burn-in	1015, total of 240 hours at +125°C	100%
Radiographic	2012	100%

- 4.4.4 <u>Group D inspection</u>. The group D inspection end-point electrical parameters shall be as specified in table IIA herein.
- 4.4.5 <u>Group E inspection</u>. Group E inspection is required only for parts intended to be marked as radiation hardness assured (see 3.5 herein). RHA levels for device classes B, S, Q, and V shall be M, D, R, and H and for device class M shall be M and D. RHA quality conformance inspection sample tests shall be performed at the RHA level specified in the acquisition document.
 - a. RHA tests for device classes B and S for levels M, D, R, and H or for device class M for levels M and D shall be performed through each level to determine at what levels the devices meet the RHA requirements. These RHA tests shall be performed for initial qualification and after design or process changes which may affect the RHA performance of the device.
 - b. End-point electrical parameters shall be as specified in table IIA herein.
 - c. Prior to total dose irradiation, each selected sample shall be assembled in its qualified package. It shall pass the specified group A electrical parameters in table I for subgroups specified in table IIA herein.
 - d. For device classes M, B, and S, the devices shall be subjected to radiation hardness assured tests as specified in MIL-M-38510 for RHA level being tested, and meet the postirradiation end-point electrical parameter limits as defined in table I at T_A = +25°C ±5 percent, after exposure.
 - e. Prior to and during total dose irradiation testing, the devices shall be biased to establish a worst case condition as specified in the radiation exposure circuit.
 - f. For device classes M, B, and S, subgroups 1 and 2 in table V, method 5005 of MIL-STD-883 shall be tested as appropriate for device construction.
 - g. When specified in the purchase order or contract, a copy of the RHA delta limits shall be supplied.

STANDARDIZED MILITARY DRAWING	SIZE A		5962-87668
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL	SHEET 23

DESC FORM 193A JUL 91

30 9004708 0010676 737 🖿

- 5. PACKAGING
- 5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-M-38510 for device classes M, B, and S and MIL-I-38535 for device classes Q and V.
 - 6. NOTES
- 6.1 <u>Intended use</u>. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.
- 6.1.1 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.
 - 6.1.2 Substitutability. Device classes B and Q devices will replace device class M devices.
- 6.2 <u>Configuration control of SMD's</u>. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished in accordance with MIL-STD-481 using DD Form 1693, Engineering Change Proposal (Short Form).
- 6.3 <u>Record of users</u>. Military and industrial users shall inform Defense Electronics Supply Center when a system application requires configuration control and which SMD's are applicable to that system. DESC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronic devices (FSC 5962) should contact DESC-ECC, telephone (513) 296-6022.
- 6.4 <u>Comments</u>. Comments on this drawing should be directed to DESC-ECC, Dayton, Ohio 45444, or telephone (513) 296-8525.
 - 6.5 Symbols, definitions, and functional descriptions. See vendor's data book.
- 6.6 One part one part number system. The one part one part number system described below has been developed to allow for transitions between identical generic devices covered by the four major microcircuit requirements documents (MIL-M-38510, MIL-H-38534, MIL-I-38535, and 1.2.1 of MIL-STD-883) without the necessity for the generation of unique PIN's. The four military requirements documents represent different class levels, and previously when a device manufacturer upgraded military product from one class level to another, the benefits of the upgraded product were unavailable to the Original Equipment Manufacturer (OEM), that was contractually locked into the original unique PIN. By establishing a one part number system covering all four documents, the OEM can acquire to the highest class level available for a given generic device to meet system needs without modifying the original contract parts selection criteria.

Military documentation format	Example PIN under new system	Manufacturing source listing	Document <u>Listing</u>
New MIL-M-38510 Military Detail Specifications (in the SMD format)	5962-XXXXXZZ(B or \$)YY	QPL-38510 (Part 1 or 2)	MIL-BUL-103
New MIL-H-38534 Standardized Military Drawings	5962-XXXXXZZ(H or K)YY	QML-38534	MIL-BUL-103
New MIL-I-38535 Standardized Military Drawings	5962-XXXXXZZ(Q or V)YY	QML-38535	MIL-BUL-103
New 1.2.1 of MIL-STD-883 Standardized	5962-XXXXXZZ(M)YY	MIL-BUL-103	MIL-BUL-103

- 6.7 Sources of supply.
- 6.7.1 Sources of supply for device classes B and S. Sources of supply for device classes B and S are listed in QPL-38510.
- 6.7.2 Sources of supply for device classes Q and V. Sources of supply for device classes Q and V are listed in QML-38535. The vendors listed in QML-38535 have submitted a certificate of compliance (see 3.6 herein) to DESC-ECC and have agreed to this drawing.
- 6.7.3 Approved sources of supply for device class M. Approved sources of supply for class M are listed in MIL-BUL-103. The vendors listed in MIL-BUL-103 have agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to and accepted by DESC-ECC.

STANDARDIZED MILITARY DRAWING	SIZE A		5962-87668
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL C	SHEET 24

DESC FORM 193A JUL 91

∞ 9004708 00l0677 673 **■**

APPENDIX

PIN SUPERSESSION INFORMATION

10. SCOPE

10.1 Scope. This appendix contains the PIN supersession information to support the one part-one part number system. For new system designs, after the date of this document the NEW PIN shall be used in lieu of the OLD PIN. For existing system designs prior to the date of this document, the NEW PIN can be used in lieu of the OLD PIN. This is a mandatory part of the document. The information contained herein is intended for compliance.

20. APPLICABLE DOCUMENTS

This section is not applicable to this appendix.

30. PIN SUPERSESSION DATA

NEW PIN	OLD PIN
5962-8766801MXX 5962-8766801MYX	5962-8766801XX 5962-8766801YX
5962-8766802MXX	5962-8766802XX
5962-8766802MYX	5962-8766802YX
5962-8766803MXX	5962-8766803XX
5962-8766803MYX	5962-8766803YX
5962-8766804MXX	5962-8766804XX
5962-8766804MYX	5962-8766804YX

STANDARDIZED MILITARY DRAWING	SIZE		5962-87668
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL C	SHEET 25

DESC FORM 193A

JUL 91

9004708 0010678 50T **=**